	<b>INFORMATION DISCLOSURE CITATION</b> (Use several sheets if necessary)		Docket Number (Optional) <b>11188.00</b>	Application Number <b>10/039,518</b>
			Applicant(s) <b>Kyung J on Han et al.</b>	
			Filing Date <b>08 November 2001</b>	Group Art Unit <b>2818</b>



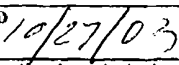
**U.S. PATENT DOCUMENTS**

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

**FOREIGN PATENT DOCUMENTS**

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO

**OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)**

	M	Brown, William D. and Brewer, Joe E., eds., Nonvolatile Semiconductor Memory Technology: A Comprehensive Guide to Understanding and Using NVSM Devices, IEEE Press, New York, 1998, pp. 69, 105, 107-108, 203, 213-217, 226-227, 235, 239-241, 244, 247, 279-281.
<b>EXAMINER</b>		<b>DATE CONSIDERED</b>
		
EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609, Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.		